PUSH-PULL 5 MHz to 210 MHz HIGH LINEARITY InGaP HBT AMPLIFIER

Package: SOIC-8



Product Description

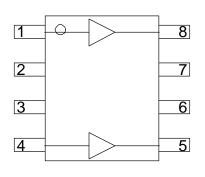
RFMD

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RFMD's CGR-0218Z is a high performance InGaP HBT MMIC Amplifier designed with the InGaP process technology for excellent reliability. A Darlington configuration is utilized for broadband performance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. The CGR-0218Z contains two amplifiers for use in wideband push-pull CATV amplifiers requiring excellent second order performance. The second and third order non-linearities are greatly improved in the push-pull configuration.



Amplifier Configuration



Features

- 5V Single Supply
- Excellent Linearity
- Two Amplifiers in Each SOIC-8 Package Simplify Push-Pull PC Board Layout
- SOIC-8 Package
- Available in Lead-Free, RoHS Compliant Packaging

Applications

- CATV Head Ends
- CATV Line Drivers
- DOCSIS Cable Modems

Parameter	Specification			Unit	Condition	
Parameter	Min. Typ.		Max.	Unit	Condition	
Small Signal Gain		17.3		dB	5MHz to 210MHz	
Gain Flatness		±0.2		dB	5MHz to 210MHz	
OIP ₃		42		dBm	5MHz to 210MHz, Tone Spacing=1MHz, P _{OUT} per tone=+6dBm	
P1dB		23		dBm	5 MHz to 210 MHz	
Input Return Loss		22		dB	5MHz to 210MHz	
Output Return Loss		22		dB	5 MHz to 210 MHz	
Noise Figure, Balun Insertion Loss Included		4.0		dB	5 MHz to 210 MHz	
CSO		80		dBc	7 Ch, Flat Tilt, +50dBmV	
СТВ		67		dBc	7 Ch, Flat Tilt, +50dBmV	
XMOD		66		dBc	7 Ch, Flat Tilt, +50dBmV	
Device Operating Voltage		5.0		V		
Device Operating Current		217		mA	5V V _{CC}	
Thermal Resistance (Junction to Lead)		30		°C/W Junction to case slug		

Test Conditions: V_{CC}=5V, I_D=217 mA Typ., T_L=25°C, Z_S=Z_L=75 Ω , Push Pull Application Circuit

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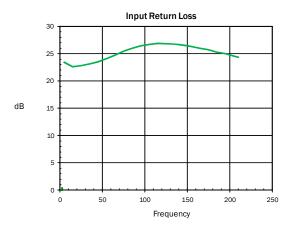
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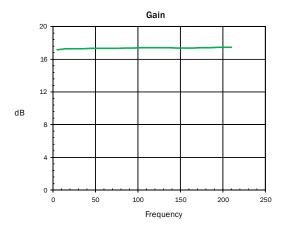


Absolute Maximum Ratings

0		
Parameter	Rating	Unit
Max Device Current (I _D)	300	mA
Max Device Voltage (V _D)	6.0	V
Max RF Input Power	18	dBm
Max Junction Temp (T _J)	150	°C
Operating Temp Range (T _L)	-40 to +85	°C
Max Storage Temp	150	°C
Min Storage Temp	-40	°C

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one. Bias Conditions should also satisfy the following expression: $I_DV_D < (T_J - T_L)/R_{TH}$, j-l and $T_L = T_{LEAD}$





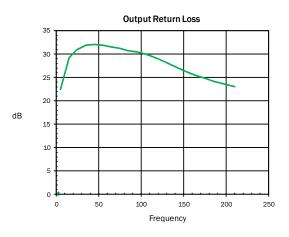


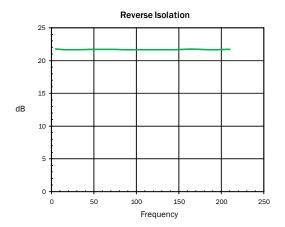
Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical perfor-mance or functional operation of the device under Absolute Maximum Rating condi-tions is not implied.

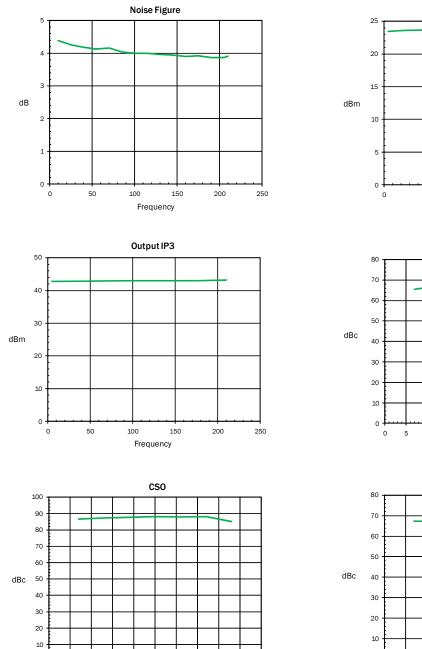
RoHS status based on EUDirective2002/95/EC (at time of this document revision).

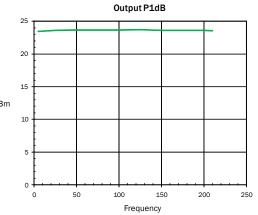
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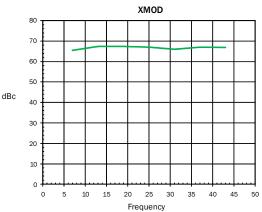


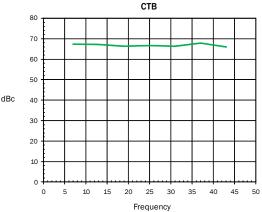












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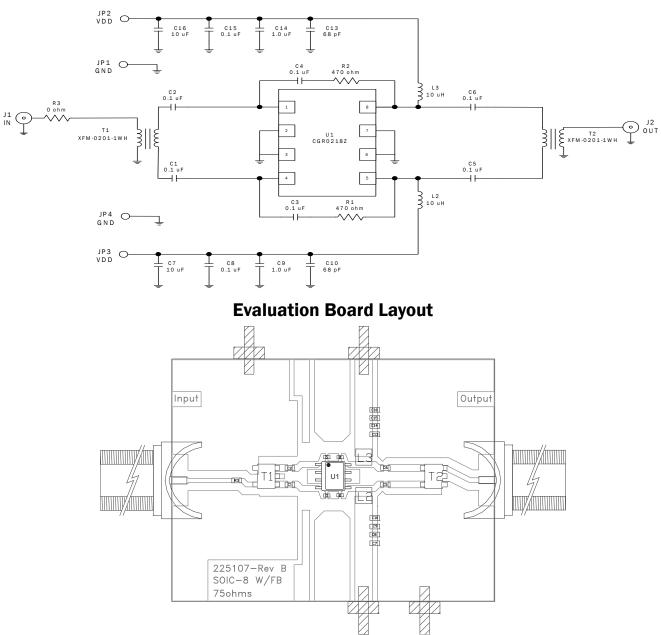
0 -

0 5

10 15 20 25 30 35 40 45 50

Frequency





Evaluation Board Schematic

Value	QTY	Location		
68 pF	2	C10, C13		
0.1uF 8		C1, C2, C3, C4, C5, C6, C8, C15		
1.0uF 2		C9, C14		
10uF	2	C7, C10		
0Ω 1		R3		
470Ω 2		R1, R2		
10uH 2		L2, L3		
RFMD™ XFM-0201-1WH 2		T1, T2		

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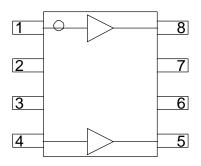


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Pin	Function	Description			
1	RF IN	RF input pin. External DC blocking capacitor is required.			
2, 3, 6, 7	GND	Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible.			
4	RF IN	Same as pin 1.			
5	RF OUT/VCC	RF output and bias pin (open collector).			
8	RF OUT/VCC	Same as pin 5.			
EPAD	GND	Exposed area on the bottom side of the package must be soldered to the ground plane of the board for optimum thermal and RF performance. Several vias should be located under the EPAD as shown in the recommended land pattern.			

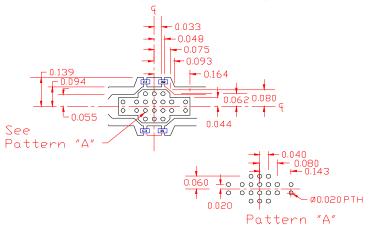
Pin Out

Amplifier Configuration



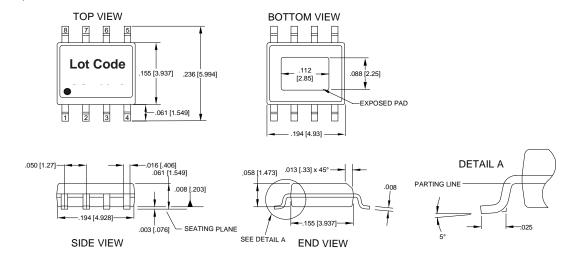


Suggested Pad Layout



Package Drawing and Marking Package Type: SOIC-8

Dimensions in inches (millimeters) Refer to drawing posted at www.rfmd.com for tolerances.



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Ordering Information

0						
Part Number	Description	Reel Size (in.)	Devices/Reel			
CGR0218ZSB	5pcs Sample Bag	NA	NA			
CGR0218ZSQ	25pcs Sample Bag	NA	NA			
CGR0218ZSR	Lead Free, RoHS Compliant	7	100			
CGR0218ZTR7	Lead Free, RoHS Compliant	7	750			
CGR0218ZTR13	Lead Free, RoHS Compliant	13	2500			
CGR0218PCBA-410	218PCBA-410 5 MHz to 210 MHz Evaluation Board		NA			

